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(54) **HIGH LOSS MODULATION ACOUSTO-OPTIC Q-SWITCH FOR HIGH POWER MULTIMODE LASER**

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(*) Notice: This patent issued on a continued prosecution application filed under 37 CFR 1.53(d), and is subject to the twenty year patent term provisions of 35 U.S.C. 154(a)(2).

Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 0 days.

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(51) **Int. Cl.**⁷ **H01S 3/117; H01S 3/30**

(52) **U.S. Cl.** **372/13; 372/3**

(58) **Field of Search** **372/13, 3**

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Primary Examiner—Paul Ip

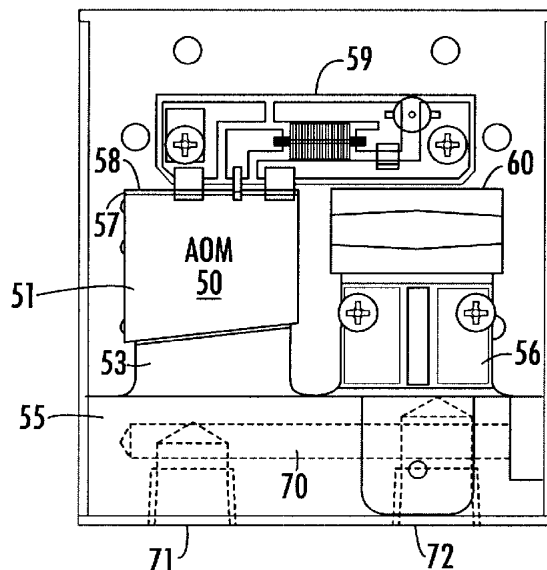
Assistant Examiner—Cornelius H. Jackson

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(57) **ABSTRACT**

A Q-switch modulator for a high power laser having a randomly polarized output beam and large divergence angle employs a cascaded arrangement of longitudinal mode acousto-optic modulators, each of which has a Raman Nath or near Raman Nath interaction length. The modulators are optically cascaded such that the distance the randomly polarized laser beam travels through the modulators is effectively confined to the sum of the non coherent interaction lengths thereof. Due to the substantial power level of the laser output, there is heating of the bulk material, which usually results in a shift in the Bragg angle. This has minimal if any effect on the shorter interaction length of the Q-switch modulator of the invention. Also, heating of the bulk material is countered by the incorporation of cooling fluid channels in a heat sink support block coupled in thermal communication with the bulk material. The heat sink support structure is configured to be effectively mechanically floating with respect to a support housing for the Q-switch.

30 Claims, 5 Drawing Sheets



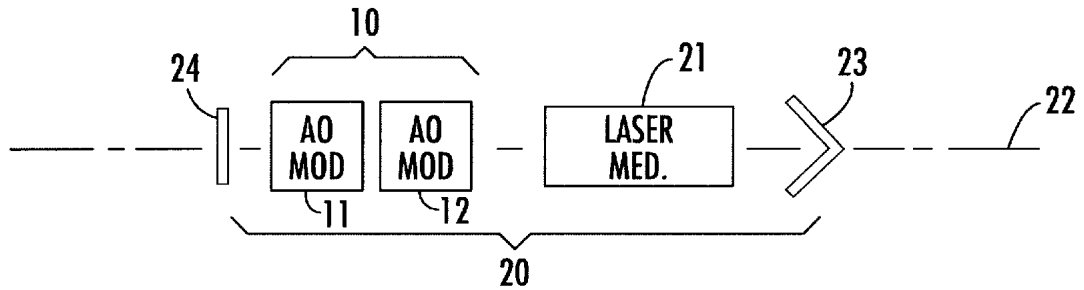


FIGURE 1

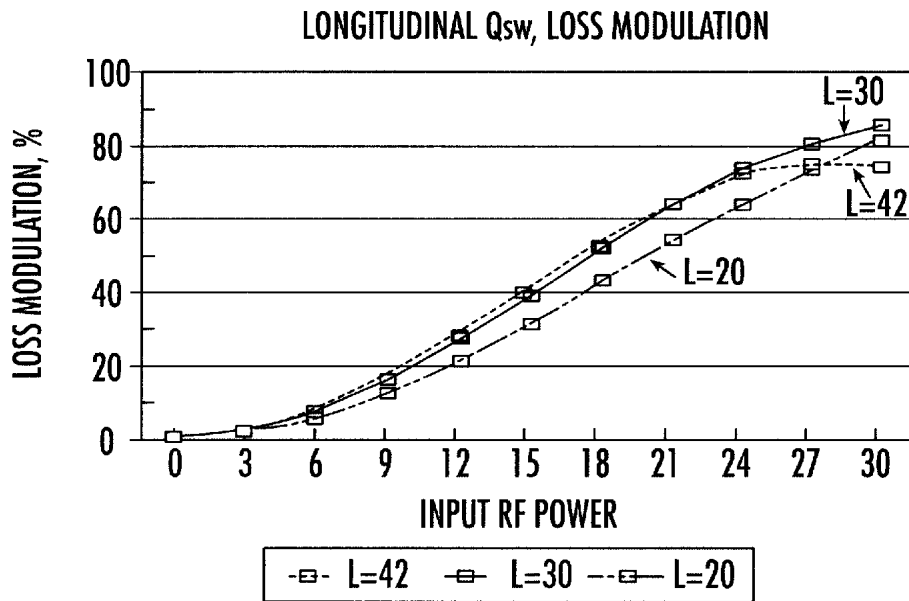


FIGURE 2

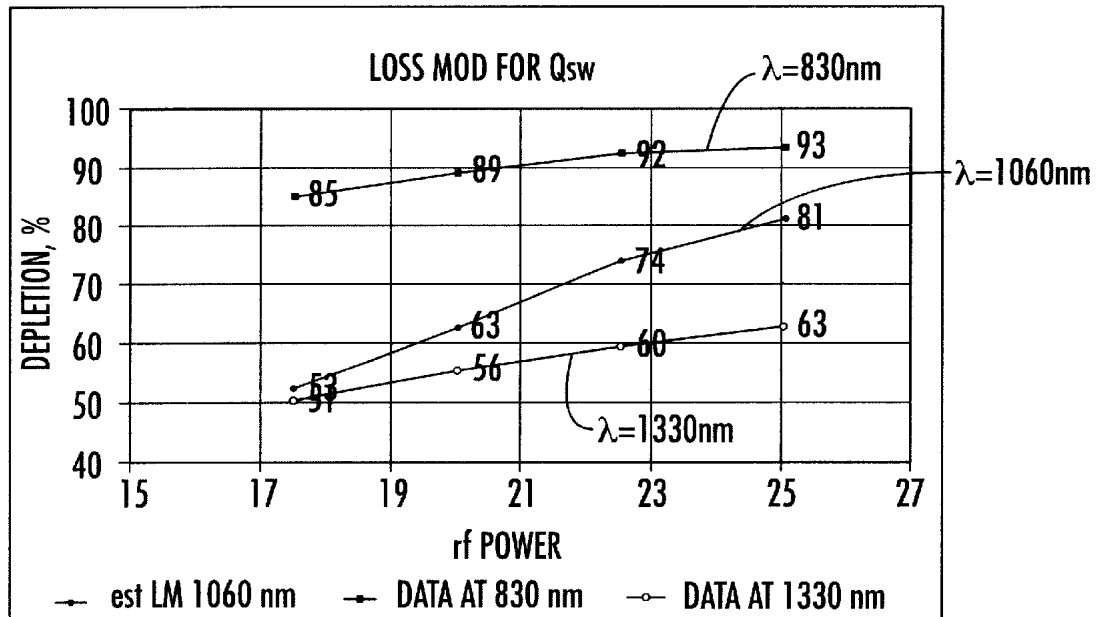


FIGURE 3

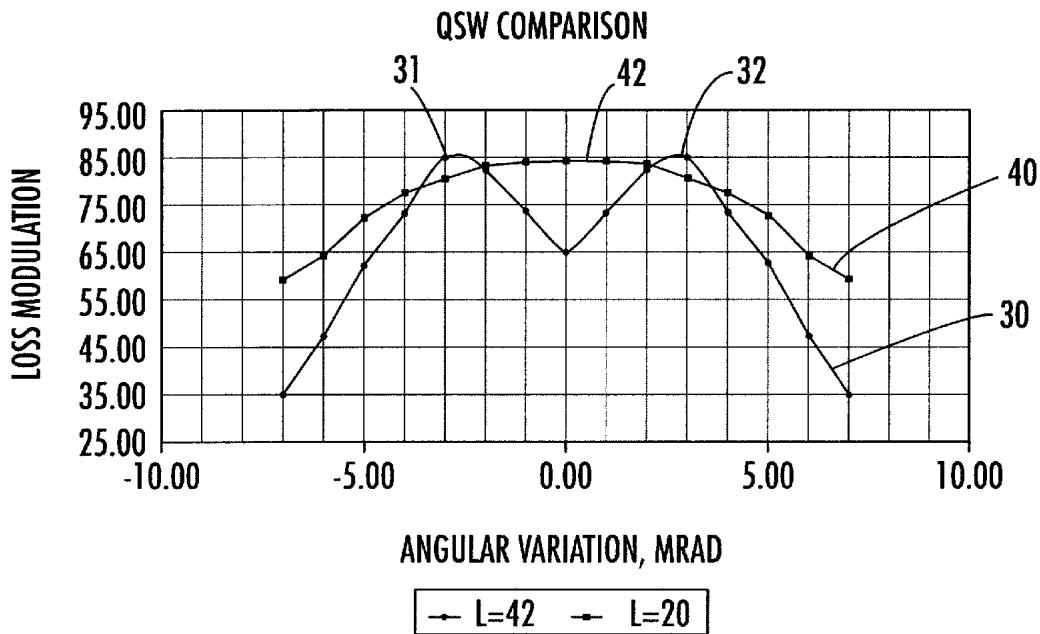


FIGURE 4

FIGURE 6

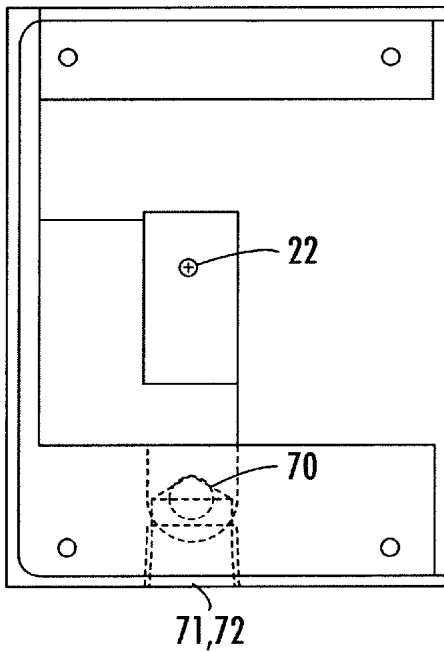
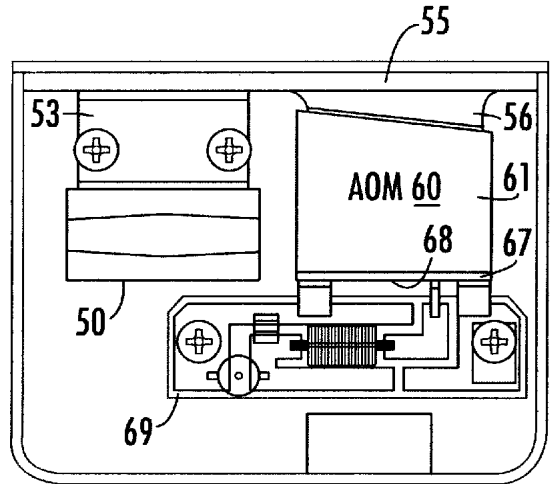


FIGURE 7

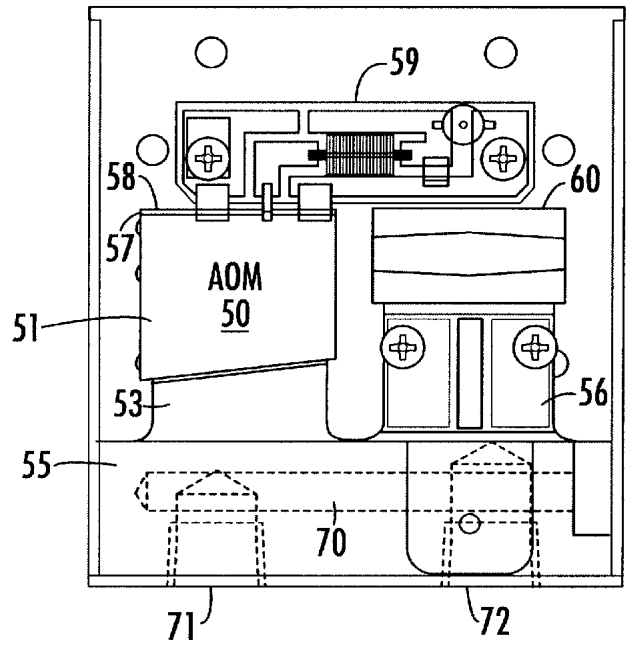


FIGURE 5

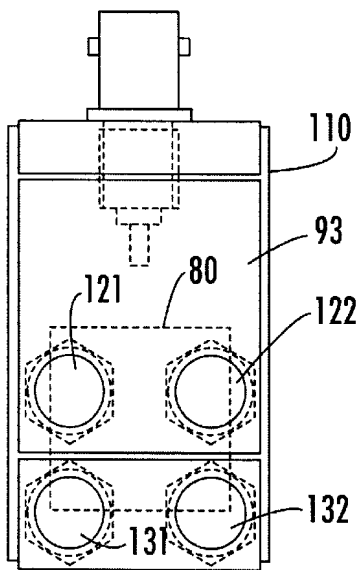


FIGURE 10

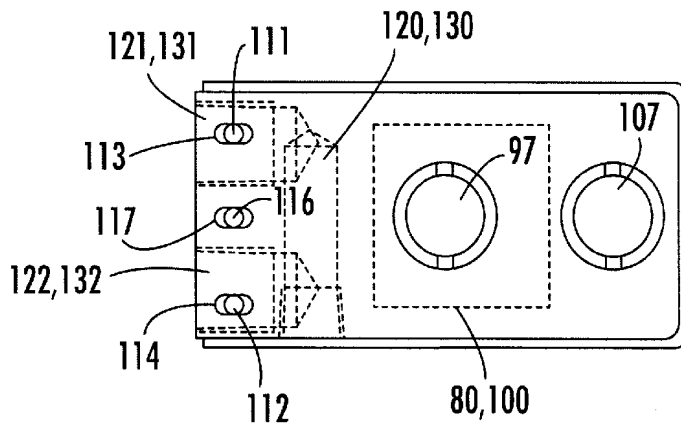


FIGURE 9

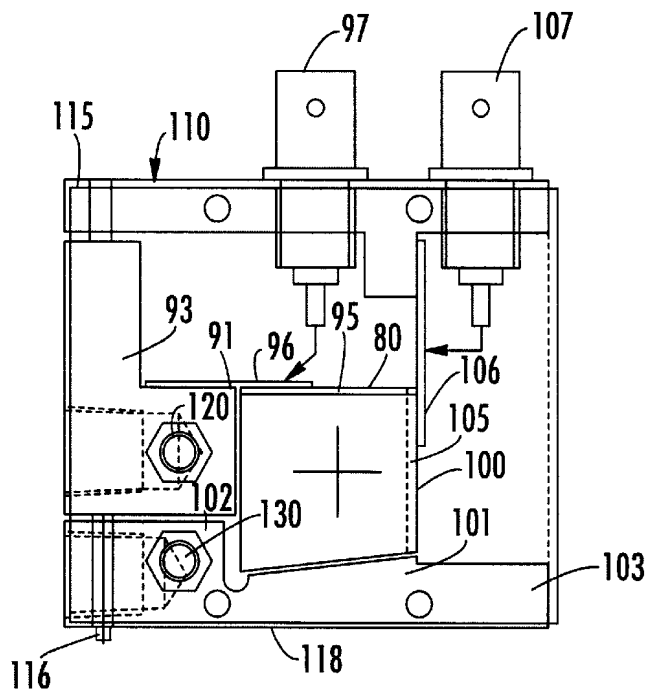


FIGURE 8

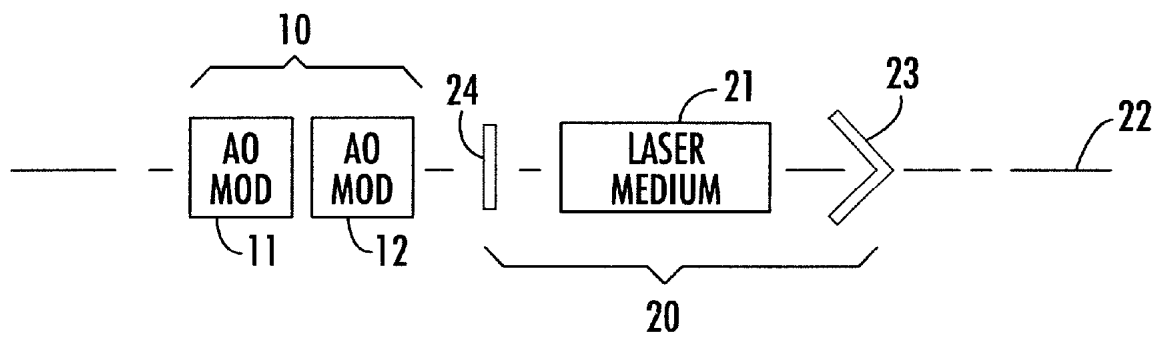


FIGURE 11

HIGH LOSS MODULATION ACOUSTO- OPTIC Q-SWITCH FOR HIGH POWER MULTIMODE LASER

CROSS-REFERENCE TO RELATED APPLICATION

The present application claims the benefit of copending U.S. Provisional Patent Application Ser. No. 60/105,156, filed Oct. 21, 1998, entitled: "High Loss Modulation Acousto-Optic Q-Switch for High Power Multimode Laser," by Eddie H. Young et al, assigned to the assignee of the present application and the disclosure of which is incorporated herein.

FIELD OF THE INVENTION

The present invention relates in general to laser beam modulation, and is particularly directed to a new and improved mechanism for (Q-switch) modulating a high power laser, such as multimode laser having a randomly polarized output beam and large divergence angle. The Q-switch mechanism of the invention employs a plurality of longitudinal mode acousto-optic modulators, each of which has a relatively short, Raman Nath or near Raman Nath based non-coherent interaction length, and being optically cascaded such that the distance the randomly polarized laser beam travels through the modulators is effectively confined to the sum of the non-coherent interaction lengths thereof.

BACKGROUND OF THE INVENTION

Acousto-optic Q-switches for controllably modulating (e.g., ON-OFF switching) randomly polarized laser beams have customarily been installed within the Fabry-Perot etalon cavity of the laser, and are controllably operative to variably and selectively modify the optical loss within the laser resonator cavity, thereby controlling initiation, amplitude and duration of the laser output beam. For 'high-loss' modulation, depletion in excess of 75% and usually in a range of at least 85-95% is necessary to prevent the laser cavity from lasing under high gain and intense pumping conditions.

For achieving high power, multimode operation is necessary. However, in a multimode operation, the laser beam is non-Gaussian and has a substantial divergence angle (on the order of five to ten milliradians or higher). This mandates that the interaction distance through the Q-switch medium be relatively long, in order to achieve high efficiency. This increase in modulator length is in conflict with the condition that, in order to satisfy the coherence requirement in an increased length acousto-optic medium, the acceptance angle must be decreased.

As a non-limiting example, for a continuous wave laser producing an output wavelength of 1.06 microns, a typical acousto-optic Q switch may be made of fused silica and operates at a frequency of 27 MHz. For longitudinal wave mode operation, the fused silica medium may have a height of 3.5 mm, a length of 42 mm, and an acousto-optic Q of 4.21. For shear wave mode operation, the fused silica device may have a height of 3.5 mm, a length of 42 mm, and an acousto-optic Q of 10.6.

Because the loss modulation efficiency for a longitudinal mode fused silica Q-switch is higher for vertical polarization than it is for horizontal polarization, it would seem that two orthogonally polarized devices might be employed to provide high loss modulation for a randomly polarized laser. However, because currently available Q switches have a

relatively high acousto-optic Q value, they are not optimum, and are unable to effectively quench high power lasers whose outputs may be well over one hundred watts and have a divergence angle on the order of five milliradians or more.

Moreover, although both conventional longitudinal mode and shear mode Q-switches are capable of providing high loss modulation, as long as the laser beam is coincident with the Bragg angle of the switch, they suffer a significant reduction in efficiency when the laser beam is not aligned with the Bragg angle. This results in a substantial reduction in loss modulation efficiency for high power, multimode laser applications, whose typical five milliradians or greater divergence angle causes Bragg angle misalignment of some portion of the beam.

While this problem might seem resolvable by placing two identical Q-switches in the laser cavity to take advantage of the cumulative loss modulation effect, it has been observed that installing two identical Q-switches in the resonant cavity of a high power, multi-mode laser results in a substantial reduction in output beam power. This laser output power reduction is due to the fact that the 'windows' through the two Q-switches are of the same path length and parallel to each other along the beam axis. As a result, the etalon effect restricts the number of longitudinal modes that can be supported within the cavity, thereby causing a reduction in laser output power.

For an illustration of non-limiting examples of literature describing various conventional Q-switch arrangements, attention may be directed to the following U.S. Pat. Nos.: 5,268,911 to E. Young; 4,979,176 to E. Young et al; 5,197,074 to D. Emmons et al; Re. 34,192 to T. Baer; 4,930,901 to J. Johnson et al; 4,337,442 to M. Mauck; and 5,130,995 to W. Grossman et al.

SUMMARY OF THE INVENTION

In accordance with the present invention, the desire to provide a high modulation loss efficiency, high acceptance angle, Q-switch for a high power (multimode) laser, whose output beam is randomly polarized and has a substantial divergence angle is successfully achieved by a cascaded arrangement of orthogonally polarized longitudinal mode acousto-optic modulators, each having a relatively short, Raman Nath or near Raman Nath-based non-coherent interaction length. By relatively short, Raman Nath or near Raman Nath-based non-coherent interaction length is meant that the beam travel path through a respective modulator's bulk material is considerably less than that required for proper Q-switch operation for a well collimated beam at a given power level, yet achieves a loss modulation efficiency that is sufficiently high to prevent the laser cavity from lasing under high gain and intense pumping conditions, even when the incident beam has a relatively large acceptance angle (on the order of five mrad or more).

The relatively short, Raman Nath or near Raman Nath Q-switch mechanism of the invention incorporates more Raman Nath or near Raman Nath interaction with the traveling acoustic wave in the bulk material. The laser beam is scattered into multiple orders, with the laser beam set at normal incidence, rather than being aligned with the Bragg angle, thereby allowing a relatively large acceptance angle (on the order of five mrad or more). This is very advantageous when the Q-switch is employed to extinguish laser beams with a large angular divergence. Also, the relatively short Raman Nath or near Raman Nath interaction length means that the overall intra-cavity length can be reduced for narrower Q-switch pulse applications.

The cascaded AO Q-switch arrangement of the invention contains a plurality (e.g., pair) of orthogonally polarized longitudinal mode acousto-optic modulators, each of which has a prescribed, relatively short, Raman Nath or near Raman Nath interaction length, that physically and optically 'stacked' relatively close to one another, so that the overall beam travel distance therethrough is effectively confined to the sum of the respective non-coherent interaction lengths thereof. The modulators may be formed as discrete devices or they may be integrated within the same acousto-optic bulk material.

Due to the substantial power level of a high power laser with which the invention is employed, there is unavoidable heating of the bulk material, which usually results in a shift in the Bragg angle. Although this adversely affects the performance of a device having a long interaction length, it has minimal effect on the shorter interaction length of the Q-switch modulator of the invention. Moreover, the actual heating of the bulk material is countered by the incorporation of cooling fluid channels in a heat sink coupled in thermal communication with the bulk material.

The inherent heating of the bulk material that results from the substantial power level of the laser may be effectively countered by incorporating cooling fluid channels in a heat sink support block to which the bulk material of each of the cascaded orthogonally polarized Q-switch devices is mounted. The support and cooling arrangement for a cascaded arrangement may be configured to support and cool the modulators as discrete components, or as devices integrated within the same acousto-optic bulk material. In the integrated bulk support and cooling arrangement, in addition to the provision of an internal channel for the passage of a cooling fluid (e.g. water), the heat sink components of the packaging architecture for the two integrated wide acceptance angle Q-switch modulators are configured to be effectively mechanically floating with respect to the support housing, so as to reduce the build-up of thermally induced stresses.

In addition to being non-coherently driven in a longitudinal mode configuration, the AOM devices may be non-coherently driven with respectively different frequencies for shear mode acoustic waves. In this mode of operation, the minimum frequency difference requires a time bandwidth product of one or greater.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 diagrammatically illustrates the architecture of a laser system that employs a cascaded Q-switch arrangement of the invention within the laser cavity;

FIG. 2 is a graphical plot of loss modulation versus input RF power for three different Q-switch lengths;

FIG. 3 is a set of measured data plots of variation in depletion (%) vs. RF power for a wide acceptance angle Q-switch of the invention having a Raman Nath or near Raman Nath interaction length of 20 mm;

FIG. 4 is a graphical comparison in the loss modulation efficiency for variations in angular divergence off an axis normal to the front face of the bulk material of a wide acceptance angle Q-switch architecture;

FIGS. 5, 6 and 7 are respective top, end and front views of a support and cooling arrangement for a cascaded arrangement of discrete wide angle acceptance Q-switch devices;

FIGS. 8, 9, and 10 are respective end, top, and side views of a support and cooling arrangement for wide angle accep-

tance Q-switch devices integrated within the same acousto-optic bulk material; and

FIG. 11 shows the placement of the cascaded acousto-optic (AO) Q-switch arrangement of the present invention outside a laser resonator used as a loss modulation device.

DETAILED DESCRIPTION

FIG. 1 diagrammatically illustrates the architecture of a high power, multimode laser system having a cascaded acousto-optic (AO) Q-switch arrangement 10 of the present invention installed within a laser resonator 20. The resonator 20 is shown as including a pumped high power laser medium 21, such as, but not limited to a YAG laser, a Homien YAG laser operating at 2.1 microns, and an Erbium YAG laser operating at 2.94 microns. The etalon length of the resonator 20 along its optical axis 22 is defined by the optical cavity separation between a retro-reflector 23 and an output beam exit mirror 24. The pumped laser medium 21 produces a multimode output beam having a substantial divergence angle (e.g., a divergence angle lying in a range of from zero to ten mrad) and typically on the order of at least five mrad.

The cascaded AO Q-switch arrangement 10 contains a plurality of orthogonally polarized longitudinal mode acousto-optic modulators, e.g., a pair of modulators shown at 11 and 12, each of which has a prescribed, relatively short, Raman Nath or near Raman Nath interaction length. For a non-limiting example of an article describing the Raman Nath or near Raman Nath property, attention may be directed to the article by W. Klein et al, entitled: "Unified Approach to Ultrasonic Light Diffraction," IEEE transactions on Sonics and Ultrasonics Vol. SU-14, No. 3, July 1967, pp 123-134.

The AO modulators 11 and 12 are physically and optically 'stacked' relatively close to one another, so that the overall beam travel distance therethrough is effectively confined to the sum of the respective non-coherent interaction lengths thereof. As will be described below with reference to the support and cooling packaging structures shown in FIGS. 5-10, the modulators 11 and 12 may be formed as discrete devices or they may be integrated within the same acousto-optic bulk material.

As pointed out above, by relatively short Raman interaction length is meant that the beam travel path through a respective modulator's bulk material (e.g., fused silica) is considerably less than that required for proper Q-switch operation for a well collimated beam at a given power level, yet achieves a loss modulation efficiency that is sufficiently high to prevent the laser cavity from lasing under high gain and intense pumping conditions, even when the incident beam has a relatively large acceptance angle (on the order of five mrad or more). Namely, contrary to the case of a well collimated (effectively non-diverging) beam, that allows Bragg angle alignment over a sufficiently long interaction distance for high loss modulation efficiency (e.g., Q=8 or higher) in a high power (multimode) laser, on the other hand, where the optical energy has substantial divergence (on the order of five mrad or more), such a long 'coherent' interaction distance is actually not helpful.

Investigation by the inventors has revealed that the shorter Raman Nath or near Raman Nath interaction length of the invention incorporates more Raman Nath or near Raman Nath interaction with the traveling acoustic wave in the bulk material, and the laser beam is scattered into multiple orders, with the laser beam set at normal incidence, rather than being aligned with the Bragg angle, thereby allowing the relatively large acceptance angle (e.g., for applications

where $Q=4$ or less). This attribute of the reduced length modulator is very advantageous when the Q-switch is employed to extinguish laser beams with a large angular divergence. Also, the relatively short Raman Nath or near Raman Nath interaction length means that the overall intra-cavity length can be reduced for narrower Q-switch pulse applications.

Due to the substantial power level, there is unavoidable heating of the bulk material, which usually results in a shift in the Bragg angle. Although this would normally adversely affect the performance of a device having a long interaction length (which requires strict adherence to Bragg angle alignment), it has minimal or no effect on the shorter interaction length of the Q-switch modulator of the invention (which enjoys a wide acceptance angle for the incident laser beam). Moreover, the actual heating of the bulk material is countered by the incorporation of cooling fluid channels in a heat sink coupled in thermal communication with the bulk material.

For a continuous wave multimode laser having an output beam wavelength of 1.06 microns, at a power level of 30 watts, as a non-limiting example, the (fused silica) bulk material of each of the longitudinal mode acousto-optic Q switches **11** and **12** may be driven by a switching signal having an RF frequency of 27 MHz applied to a transducer **14** bonded to a wave-launching surface of the silica bulk. The fused silica medium of each modulator may be configured as a generally solid rectangular bulk member, having a side edge height and width of 3.5 mm, and a length along the optical axis **22** that is considerably shorter than the relatively long coherent interaction length (e.g., 42 mm), described above.

As a non-limiting example, the Raman Nath or near Raman Nath interaction length of each of the two orthogonally polarized modulators may lie in a range of 20–30 mm having associated AO Q values in a range of 1.9–2.8. At an interaction length of 20 mm and an AO Q of 1.9 per modulator, measurements have revealed that a cascaded pair of such elements is capable of providing an average loss modulation efficiency of 82.3% or higher. At an interaction length of 30 mm and an AO Q of 2.8 per modulator, measurements have revealed that a cascaded intra-cavity pair of wide acceptance angle devices is capable of providing an average loss modulation efficiency of 85.9% or higher. These values are well in excess of the above referenced 75% depletion value necessary to prevent the laser cavity from lasing under high gain and intense pumping conditions.

FIG. 2 is a graphical plot of loss modulation (percent) versus input RF power for three different Q-switch lengths: 42 mm; 30 mm and 20 mm. At a drive power of 30 watts, the respective efficiencies are 74.5%, 86% and 82.3%. FIG. 3 is a set of measured data plots of variation in depletion (%) vs. RF power for a wide acceptance angle Q-switch of the invention having a Raman Nath or near Raman Nath interaction length of 20 mm and an AO Q of 1.9 for respective beam wavelengths of 830, 1060 and 1330 nm. FIG. 4 is a graphical comparison in the loss modulation efficiency for variations in angular divergence off an axis that is normal to the front face of the bulk material of a wide acceptance angle Q-switch architecture, comprised of a cascaded pair of orthogonally polarized fused silica modulators, each having a Raman Nath or near Raman Nath interaction length of 20 mm and an AO Q of 1.9 per modulator, and a relatively large interaction length, limited acceptance angle Q-switch architecture having an interaction length of 42 mm and AO Q=3.9.

As shown by the characteristic **30** of FIG. 4, the loss efficiency of the relatively long interaction length of the limited acceptance angle device has peaks **31** and **32** (on the order of 85%) at the Bragg angle and drops off sharply on either side of the Bragg angle to a 'valley minimum' value (65%) at zero mrad. On the other hand, the reduced length Raman Nath or near Raman Nath interaction length device of the invention has a 'relatively flat' characteristic **40**, having a high efficiency peak **41** (on the order of 82%) at zero mrad and remaining above or proximate to 75% well out to five mrad. Indeed, the characteristic of the large acceptance angle Q-switch of the invention does not drop to a 65% value until a divergence angle of six mrad.

As noted above, the inherent heating of the bulk material that results from the substantial power level may be effectively countered by the incorporation of cooling fluid channels in a heat sink coupled in thermal communication with the bulk material of each of the cascaded orthogonally polarized Q-switch devices. The configuration of the support and cooling arrangement for a cascaded arrangement of discrete devices is diagrammatically illustrated in FIGS. 5–7, while a support and cooling arrangement for devices integrated within the same acousto-optic bulk material is diagrammatically illustrate in FIGS. 8–10.

More particularly, as shown in detail in the top view of FIG. 5, a first (X-axis polarization) AOM **50** has the fused silica substrate **51** thereof thermally and mechanically mounted to a first mounting mesa **53** of a heat sink (aluminum) support block **55**. An acousto-optic wave-launching transducer **57** for the X-axis acousto-Optic substrate **51** has its input electrode **58** coupled to an RF drive/tuning circuit **59**. As shown in the end view of FIG. 6, a second orthogonal (Y-axis) polarization AOM **60** has the fused silica substrate **61** thereof thermally and mechanically mounted to a second mounting mesa **56** of the heat sink (aluminum) support block **55**. As the spacing or separation between mesas **53** and **56** of the support block can be effectively minimized within practical mechanical and thermal expansion constraints, the overall distance the randomly polarized laser beam travels through the cascaded modulators is effectively confined to the sum of the non coherent interaction lengths thereof. As noted earlier, this relatively 'short' interaction length provides for a relatively short intra-cavity length for narrower Q-switch pulse applications.

An acousto-optic wave-launching transducer **67** for the (Y-axis) acousto-optic substrate **61** has its input electrode **68** coupled to RF drive/tuning circuitry **69**. The uncluttered front view of FIG. 7, shows the optical axis **22** through each of the substrates **51** and **61**. In order to cool the bulk material of each of the AOMs **50** and **60**, an internal cooling channel **70** is formed within the support block **55** adjacent to the mounting mesas **53** and **56**. The cooling channel **70** is externally coupled at ports **71** and **72** to a source of cooling fluid (e.g., water).

In the integrated bulk support and cooling arrangement of FIGS. 8–10, in addition to the provision of an internal channel for the passage of a cooling fluid (e.g. water), the heat sink components of the packaging architecture for the two integrated wide acceptance angle Q-switch modulators are configured to be effectively mechanically floating with respect to the support housing, so as to reduce the build-up of thermally induced stresses. In addition, the heat sink support components are located along separate walls of the support housing, which allows them to be independently mechanically positioned in association with the closely spaced locations of the cascaded X and Y axis modulators, that are integrated within the common acousto-optic bulk to

be effectively minimized within practical mechanical and thermal expansion constraints. As a consequence, as in the first embodiment, the overall distance the randomly polarized laser beam travels through the cascaded modulators is effectively confined to the sum of the non coherent interaction lengths thereof. The optical axis through the substrate **80** is shown at **22**.

More particularly, as shown in detail in the end view of FIG. **8**, a common fused silica substrate **80**, in which a first (X-axis polarization) AOM **90** and a second (Y-axis polarization) AOM **100** are integrated, is thermally and mechanically mounted to a first mounting mesa **91** of a first heat sink (aluminum) support block **93**. An acousto-optic wave-launching transducer **95** for the X-axis modulator **90** has its input electrode **96** coupled to an RF connector **97**, through which an RF drive signal is applied. As shown in the top view of FIG. **9**, the heat sink support block **93** is mechanically retained within a support housing **110** by way of a pair of attachment elements (e.g., screws) **111** and **112** that pass through associated elongated slots **113** and **114** in a first top wall **115** of the support housing **110**. The elongated slots allow the heat sink support block **93** to effectively 'float' within the housing **110**, so as to compensate for thermally induced stresses in the X-axis modulator **90**.

The second orthogonal (Y-axis) polarization AOM **100** is thermally and mechanically mounted to a second mounting mesa **101** of a second heat sink (aluminum) support block **103**. An acousto optic wave launching transducer **105** for the Y-axis AOM **100** has its input electrode **106** to an RF connector **107**, through which an RF drive signal therefor is applied. The separate RF connectors **97** and **107** allows for separate (parallel) RF drive signals to be applied to the respective X-axis and Y-axis modulators. Where a series RF drive for the two modulators is employed, only a single RF connector is needed. Similar to the heat support block **93**, the heat sink support block **103** is mechanically retained within the support housing **110** by way of an attachment element (e.g., screw) **116** that passes through an associated elongated slot **117** in an opposite bottom wall **118** of the support housing **110** from top wall **115**. As with heat support block **93**, the elongated slot **117** allows the heat sink support block **103** to effectively 'float' within the housing **110**, and thereby compensate for thermally induced stress build-up in the Y-axis modulator **100**.

In order to cool the bulk material of each of the AOMs **90** and **100**, respective internal cooling channels **120** and **130** are formed within the support blocks **93** and **103**. In particular, a cooling channel **120** is formed in the mesa portion **91** of the support block **93**, and a cooling channel **130** is formed in a mesa portion **102** of the support block **103**. As shown in the side view of FIG. **10**, the cooling channel **120** is externally coupled at ports **121** and **122** to a source of cooling fluid (e.g., water), while cooling channel **130** is externally coupled at ports **131** and **132** to a source of cooling fluid.

As pointed out above, the cascaded orthogonally polarized (X-Y) Q-switch architecture of the present invention may be installed either within or external to the laser cavity of a high power laser for different purposes. The substantial improvement in performance of an intracavity device has been described above with reference to FIGS. **1-4**. FIG. **11** shows the placement of the cascaded acousto-optic (AO) Q-switch arrangement **10** of the present invention outside the laser resonator **20**. As a non limiting example, in this external application, the laser beam output power may be a continuous wave output beam having a power of 300-1000 watts or higher.

In a non-limiting practical example, the cascaded modulator may have an aperture size of 16 mm, which allows for high laser output beam power; also laser beam divergence can be reduced with a larger beam diameter. For a modulator RF drive power of 60 watts, the loss modulation efficiency of a respective X-axis or Y-axis modulator is on the order of 53%. For a drive power of 80 watts, the loss modulation efficiency is increased to a value on the order of 61%. For a drive power of 100 watts, the loss modulation efficiency is increased to 66%. This latter set of parametric data means that a cascaded arrangement of X- and Y-axis devices is capable of producing a combined loss modulation efficiency of $66\%+34\%\times 66\%$, or about 88%, which is sufficient to quench (ON-OFF modulate) a high power (100 watt) laser beam.

In addition to the embodiment described above, the respective AOM devices may be non-coherently driven by using respectively different frequencies for each modulator for shear mode acoustic waves. The minimum frequency difference requires a time bandwidth product of 1 or greater. For example, for a beam width of 3.5 mm (aperture time=0.93 microseconds), a frequency difference of 1.1 MHz or greater is necessary to achieve a time bandwidth product greater than 1. If one modulator has an input drive frequency of 27.12 MHz, for example, then the other modulator needs to be driven at a frequency of 28.22 MHz or greater, or less than a frequency of 26.02 MHz or lower.

As will be appreciated from the foregoing description, the desire to provide a high modulation loss efficiency, high acceptance angle, Q-switch for a high power (multimode) randomly polarized laser is successfully achieved by a wide acceptance angle, cascaded arrangement of orthogonally polarized AOM devices, in which each AOM has a relatively short, Raman Nath or near Raman Nath interaction length. With the devices being physically and optically 'stacked' relatively close to one another, the overall beam travel distance therethrough is effectively confined to the sum of the respective non coherent interaction lengths thereof. This is not only advantageous when the Q-switch is employed to switch laser beams with large angular divergence, but the relatively short Raman Nath or near Raman Nath interaction length means that the overall intra-cavity length can be reduced for narrower Q-switch pulse applications.

While we have shown and described several embodiments in accordance with the present invention, it is to be understood that the same is not limited thereto but is susceptible to numerous changes and modifications as known to a person skilled in the art, and we therefore do not wish to be limited to the details shown and described herein, but intend to cover all such changes and modifications as are obvious to one of ordinary skill in the art.

What is claimed is:

1. A method of controllably modulating the transmission of a randomly polarized laser beam comprising the steps of:
 - (a) providing a first acousto-optic modulator having a first Raman Nath or near Raman Nath interaction length for a laser beam at a first linear polarization;
 - (b) providing a second orthogonal acousto-optic modulator having a second Raman Nath or near Raman Nath interaction length for a laser beam at a second linear polarization different from said first linear polarization; and
 - (c) cascading said second acousto-optic modulator with said first acousto-optic modulator in a beam path of said randomly polarized laser beam in an optically stacked configuration in either one of a discrete con-

struction having a common heat sink support and fused silica substrate supporting each acousto-optic modulator, each thermally and mechanically- mounted to the common heat sink, or an integrated construction having an acousto-optic bulk material, wherein each acousto-optic modulator is formed within the same acousto-optic bulk material, such that the modulations thereby of said randomly polarized laser beam do not interfere with one another and sum incoherently, and the distance said randomly polarized laser beam travels through said first and second acousto-optic modulators is effectively confined to the sum of the respective interaction lengths thereof.

2. A method according to claim 1, wherein said first and second acousto-optic modulators are configured of respectively separate acousto-optic elements.

3. A method according to claim 1, wherein said first and second acousto-optic modulators are integrated in a common acousto-optic substrate.

4. A method according to claim 1, wherein said randomly polarized laser beam is a multi-mode laser beam.

5. A method according to claim 1, wherein said randomly polarized laser beam has a divergence angle of at least four milliradians.

6. A method according to claim 1, wherein said randomly polarized laser beam has a divergence angle of at least five milliradians.

7. A method according to claim 1, wherein step (c) comprises coupling said first and second acousto-optic modulators with a cooling channel structure through which a fluid cooling said first and second acousto-optic modulators passes.

8. A method according to claim 1, wherein step (c) comprises coupling said first and second acousto-optic modulators with a heat sink support structure that is effectively mechanically floating with respect to a housing for said first and second acousto-optic modulators.

9. A method according to claim 1, wherein step (c) comprises cascading said first and second acousto-optic modulators within a laser oscillation cavity of a laser generating said laser beam.

10. A method according to claim 1, wherein step (c) comprises cascading said first and second acousto-optic modulators external of a laser oscillation cavity of a laser generating said laser beam.

11. A method according to claim 1, wherein said first and second acousto-optic modulators comprise longitudinal mode acousto-optic modulators.

12. A method according to claim 1, wherein said first and second acousto-optic modulators comprise shear mode acousto-optic modulators.

13. A method according to claim 1, wherein said second linear polarization is orthogonal to said first linear polarization.

14. A method according to claim 1, wherein transducer input drives for said first and second acousto-optic modulators are coupled to respective first and second RF signal feed ports.

15. A method according to claim 1, wherein transducer input drives for said first and second acousto-optic modulators are coupled in series to an RF signal feed port.

16. An arrangement for controllably modulating a randomly polarized laser beam comprising:

a first acousto-optic modulator having a first Raman Nath or near Raman Nath interaction length for a laser beam having a first linear polarization;

a second orthogonally acousto-optic modulator having a second Raman Nath or near Raman Nath interaction

length for a laser beam having a second linear polarization different from said first linear polarization; and wherein said first and second acousto-optic modulators are disposed in cascade along a beam path of said randomly polarized laser beam in an optically stacked configuration in either one of a discrete construction having a common heat sink support and fused silica substrate supporting each acousto-optic modulator, each thermally and mechanically mounted to the common heat sink, or an integrated construction having an acousto-optic bulk material, wherein each acousto-optic modulation is formed within the same acousto-optic bulk material, such that the modulations thereby of said randomly polarized laser beam do not interfere with one another and sum incoherently, and the distance said randomly polarized laser beam travels through said first and second acousto-optic modulators is effectively confined to the sum of the respective interaction lengths thereof.

17. An arrangement according to claim 16, wherein said first and second acousto-optic modulators are configured of respectively separate acousto-optic elements.

18. An arrangement according to claim 16, wherein said first and second acousto-optic modulators are integrated in a common acousto-optic substrate.

19. An arrangement according to claim 16, further including a cooling channel structure coupled to said first and second acousto-optic modulators and through which a fluid cooling said first and second acousto-optic modulators passes.

20. An arrangement according to claim 16, further including a heat sink support structure that is effectively mechanically floating with respect to a housing for said first and second acousto-optic modulators.

21. An arrangement according to claim 16, wherein said first and second acousto-optic modulators are cascaded within a laser oscillation cavity of a laser generating said laser beam.

22. An arrangement according to claim 16, wherein said first and second acousto-optic modulators are cascaded external of a laser oscillation cavity of a laser generating said laser beam.

23. An arrangement according to claim 16, wherein said first and second acousto-optic modulators comprise longitudinal mode acousto-optic modulators.

24. An arrangement according to claim 16, wherein said first and second acousto-optic modulators comprise shear mode acousto-optic modulators.

25. An arrangement according to claim 16, wherein said second linear polarization is orthogonal to said first linear polarization.

26. An arrangement according to claim 16, wherein transducer input drives for said first and second acousto-optic modulators are coupled to respective first and second RF signal feed ports.

27. An arrangement according to claim 16, wherein transducer input drives for said first and second acousto-optic modulators are coupled in series to an RF signal feed port.

28. An arrangement for controllably modulating a randomly polarized laser beam comprising:

a first acousto-optic modulator configured for a first linear polarization and having a first relatively short, Raman Nath or near Raman Nath interaction length for said first linear polarization that achieves a loss modulation efficiency sufficiently high to prevent the laser cavity from lasing under high gain and intense pumping

11

conditions, when an incident laser beam has an acceptance angle that is not aligned with the Bragg angle; and a second acousto-optic modulator configured for a second linear polarization orthogonal to said first linear polarization, and having a second Raman Nath or near Raman Nath interaction length for said second linear polarization that achieves a loss modulation efficiency sufficiently high to prevent the laser cavity from lasing under high gain and intense pumping conditions, when an incident laser beam has an acceptance angle that is not aligned with the Bragg angle; and wherein said first and second acousto-optic modulators are disposed in cascade along a beam path of said randomly polarized laser beam, such that modula-

12

tions thereby of said randomly polarized laser beam do not interfere with one another and sum incoherently, and the distance said randomly polarized laser beam travels through said first and second acousto-optic modulators is effectively confined to the sum of the respective interaction lengths thereof.

29. An arrangement according to claim **28**, wherein said first and second acousto-optic modulators comprise longitudinal mode acousto-optic modulators.

30. An arrangement according to claim **28**, wherein said first and second acousto-optic modulators comprise shear mode acousto-optic modulators.

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